TOSHIBA

TOSHIBA Photocoupler IRED & Photo-Triac

TLP163J

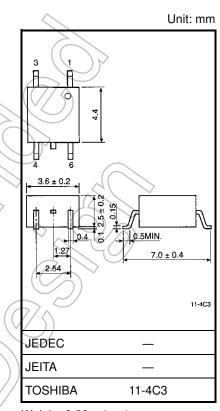
Triac Drive Programmable Controllers AC-Output Modules Solid State Relay

The TOSHIBA mini-flat coupler TLP163J is housed in a small outline package, suitable for surface-mount assembly.

The TLP163J consists of an infrared emitting diode optically coupled to a photo-triac coupler.

The TLP163J features a greater capacity to withstand external noise than that of the TLP161J.

- Zero-voltage crossing turn-on
- Peak off-state voltage: 600 V (min)
- Trigger LED current: 10 mA (max)
- On-state current: 70 mA (max)
- Isolation voltage: 2500 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349



Weight: 0.09 g (typ.)

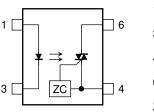
Trigger LED Current

| | Trigger LED | | |
|--------------------|-------------|------------------------------|-----------|
| Classification (*) | VT = 3 V, | Marking of Classification | |
| | Min | Max | |
| (IFT7) | | 7 | Τ7 |
| Standard | \bigcirc | 10 | T7, Blank |

*: e.g., (IFT7): TLP163J(IFT7)

Note: A part number for a certification test, use the standard part number, i.e. TLP163J(IFT7): TLP163J

Pin Configurations



- 1: Anode
- 3: Cathode
- 4: Terminal 1
- 6: Terminal 2
- ZC: Zero-cross circuit

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | | |
|---|--|---|---------------------|-------|------------|----------------------------|
| | Forward current | | lF | 50 | mA | |
| Forward current derating $(Ta \ge 53^{\circ}C)$ | | | ∆IF/°C | -0.7 | mA/°C | |
| | Peak forward current (100 μs pulse, 100 pps) | | IFP | 1 | A | |
| LED Reverse voltage | | VR | 5 | v | \bigcirc | |
| | Input power dissipation | | PD | 100 | mW | |
| | Input power dissipa $(Ta \ge 53^{\circ}C)$ | Input power dissipation derating $(Ta \ge 53^{\circ}C)$ | | -1.4 | mW/°C |) |
| | Junction temperatu | ire | Tj | 125 | .0 | |
| | Off-state output terminal voltage | | VDRM | 600 | × | |
| | On-state RMS current | Ta = 25°C | | 70 | mA | $\mathcal{A}(\mathcal{D})$ |
| Detector | | Ta = 70°C | I _{T(RMS)} | 40 | ША | \leq |
| | On-state current de $(Ta \ge 25^{\circ}C)$ | erating | ΔIŢ/°C | -0.67 | mA/°C | RA |
| | Peak on-state curre (100 μs pulse, 120 | | ITP | 2 | A | |
| | Peak non-repetitive (Pw = 10 ms) | e surge current | ITSM | 1.2 | |) |
| | Output power dissi | pation | Po | 200 | mW | |
| | Output power dissipation derating $(Ta \ge 25^{\circ}C)$ | | ∆P ₀ /°C | -2.0 | mW/°C | |
| | Junction temperature | |)) тј | 115 | °C | |
| Storage temperature range | | T _{stg} | -55 to 125 | °C | | |
| Operating temperature range | | T _{opr} | -40 to 100 | °C | | |
| Lead soldering temperature (10 s) | | T _{sol} | 260 | °C | | |
| Isolation vo | Isolation voltage (AC, 60 s, R.H. ≤ 60 %) (Note 1) | | BVS | 2500 | Vrms | |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two terminal device: Pins 1 and 3 shorted together and pins 4 and 6 shorted together.

Recommended Operating Conditions

| Characteristics | Symbol | Min | Тур. | Max | Unit |
|-----------------------|------------------|-----|------|-----|------|
| Supply voltage | VAC | _ | _ | 240 | Vac |
| Forward current | lF | 15 | 20 | 25 | mA |
| Peak on-state current | ITP | | | 1 | А |
| Operating temperature | T _{opr} | -25 | _ | 85 | °C |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Electrical Characteristics (Ta = 25°C)

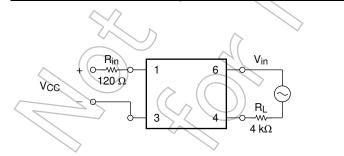
| | Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------|---|----------------|---|---------------------------|------|------|------|
| | Forward voltage | VF | I _F = 10 mA | 1.0 | 1.15 | 1.3 | V |
| LED | Reverse current | I _R | V _R = 5 V | _ | _ | 10 | μA |
| | Capacitance | Ст | V = 0 V, f = 1 MHz | / | 30 | _ | pF |
| Detector | Peak off-state current | IDRM | V _{DRM} = 600 V | $\langle \langle \rangle$ | 10 | 1000 | nA |
| | Peak on-state voltage | Vтм | I _{TM} = 70 mA | | 1.7 | 2.8 | V |
| | Holding current | lΗ | (7) | | 0.6 | — | mA |
| | Critical rate of rise of off- state voltage | dv/dt | V _{in} = 240 Vrms, Ta = 85 °C (Figure 1) | 200 | 500 | - | V/µs |
| | Critical rate of rise of commutating voltage | dv/dt(c) | Vin = 60 Vrms, IT = 15 mA (Figure 1) | _ | 0.2 | _ | V/µs |

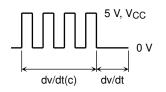
Coupled Electrical Characteristics (Ta = 25°C)

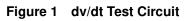
| Characteristics | Symbol | Test Condition | Min | Тур | Max | Unit |
|----------------------------|--------|---|--------|------|-----|------|
| Trigger LED current | IFT | VT = 3 V | \sim | | 10 | mA |
| Inhibit voltage | VIH | IF = Rated IFT | A) | _ | 20 | V |
| Leakage in inhibited state | Ιн | IF = Rated IFT, VT = Rated VDRM | \Box | 200 | 600 | μA |
| Turn-on time | ton | $V_{D} = 3 \rightarrow 1.5 \text{ V}, \text{ R}_{L} = 20 \Omega,$ IF = Rated IFT x 1.5 |) – | 30 | 100 | μS |
| Impulse noise durability | VN | $t_N = 1 \ \mu s$, snubber condition 120 Ω + 0.1 μ F (Note 3) | _ | 2000 | _ | V |

Isolation Characteristics (Ta = 25° C)

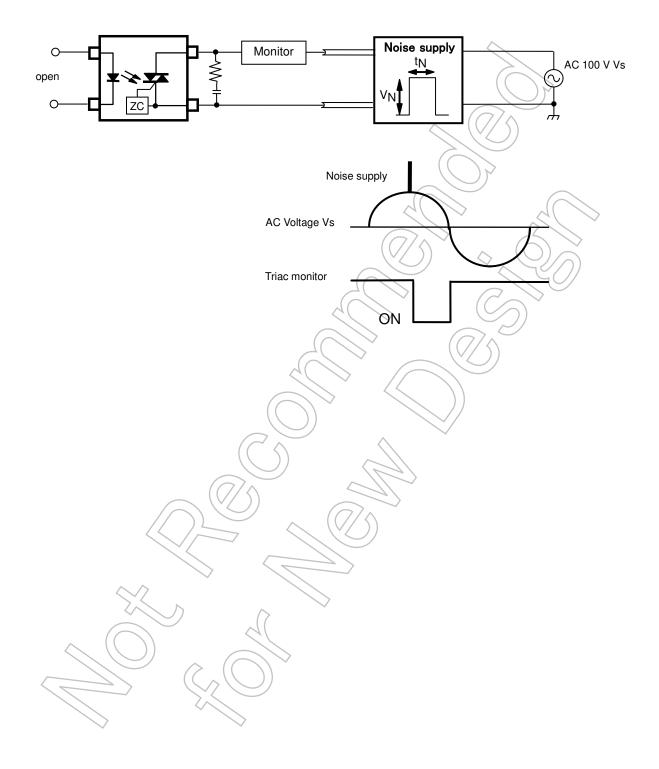
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|-------------------------------|--------|-------------------------|--------------------|------------------|-----|------|
| Capacitance (input to output) | Cs | $V_S = 0 V, f = 1 MHz$ | _ | 0.8 | _ | pF |
| Isolation resistance | Rs < | Vs = 500 V, R.H. ≤ 60 % | 1×10^{12} | 10 ¹⁴ | _ | Ω |
| Isolation voltage | BVs | AC, 60.s | 2500 | _ | _ | Vrms |







Note 3: impulse noise durability test circuit



RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
 limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
 technology products (mass destruction weapons). Product and related software and technology may be controlled under the
 applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
 U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
 except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION